



**DFLS1100** 

#### 1.0A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER **POWERDI**

## **Product Summary**

I	V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F</sub> max (V)	I <sub>R max</sub> (μΑ)
	100	1	0.77	0.35

## **Features and Benefits**

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Patented Interlocking Clip Design for High Surge Current
- Lead Free Finish, RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The DFLS1100Q-7 is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

## **Description and Applications**

This Schottky Barrier Rectifier is designed to meet the stringent requirements of automotive applications. It is ideally suited for use as:

- Polarity Protection Diode
- Re-circulating Diode
- Switching Diode

#### **Mechanical Data**

- Case: POWERDI®123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Band
- Terminals: Finish Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.01 grams (Approximate)



Top View

## Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DFLS1100-7	Commercial	POWERDI®123	3000/Tape & Reel
DFLS1100Q-7	Automotive	POWERDI®123	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



F09 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: B = 2014)M = Month (ex: 9 = September)

Data Codo Koy

Date Code Ney												
Year	2013	20	14	2015	2016	20	17	2018	2019	20	20	2021
Code	А		3	С	D		E	F	G	I	1	l
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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#### **Maximum Ratings** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	71	V
Forward Current rms (T <sub>C</sub> = +160°C, D = 0.5)	I <sub>F(RMS)</sub>	2	Α
Average Forward Current	I <sub>F(AV)</sub>	1.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	50	Α
Repetitive Peak Reverse Current $t_P$ = 2 $\mu$ s, f = 1kHz Square	I <sub>RRM</sub>	1.0	Α
Repetitive Peak Avalanche Power $t_P = 1\mu s$ , $T_J = +25^{\circ}C$	P <sub>ARM</sub>	1500	W
Non-repetitive Peak Reverse Current $t_P$ = 100 $\mu$ s Square	I <sub>RSM</sub>	1.0	Α
Critical Rate of Rise of Reverse Voltage (Rated $V_R$ , $T_J = +25$ °C)	dV/dt	10000	V/µs

## **Thermal Characteristics**

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance Junction to Soldering (Note 5)	$R_{ heta}$ JS	_	7	
Thermal Resistance Junction to Ambient (Note 6) T <sub>A</sub> = +25°C	$R_{ heta JA}$	125	_	°C/W
Thermal Resistance Junction to Case (Note 6) T <sub>A</sub> = +25°C	$R_{ heta JC}$	21	_	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to	+175	°C

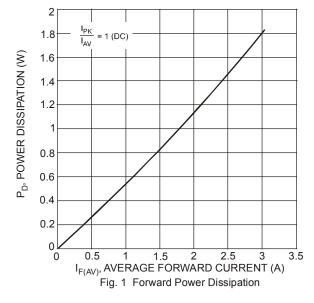
#### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

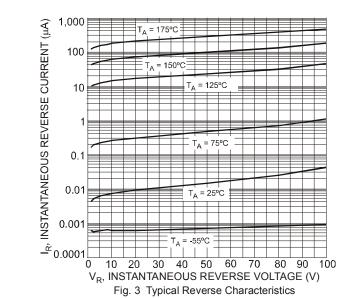
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	$V_{(BR)R}$	100	_	_	V	I <sub>R</sub> = 1mA
	VF	_	_	0.77	V	I <sub>F</sub> = 1.0A, T <sub>A</sub> = +25°C
Forward Voltage		_	0.58	0.62		I <sub>F</sub> = 1.0A, T <sub>A</sub> = +125°C
ward voltage		_	_	0.86		I <sub>F</sub> = 2.0A, T <sub>A</sub> = +25°C
		_	0.65	0.7		I <sub>F</sub> = 2.0A, T <sub>A</sub> = +125°C
	I <sub>R</sub>	_	_	0.10	μΑ	V <sub>R</sub> = 50V, T <sub>A</sub> = +25°C
		_	_	3	μΑ	V <sub>R</sub> = 50V, T <sub>A</sub> = +65°C
Leakage Current (Note 7)		_	_	15	μΑ	V <sub>R</sub> = 50V, T <sub>A</sub> = +85°C
		_	_	0.35	μΑ	V <sub>R</sub> = 100V, T <sub>A</sub> = +25°C
			_	0.35	mA	V <sub>R</sub> = 100V, T <sub>A</sub> = +125°C
Total Capacitance	C <sub>T</sub>	_	36	_	pF	$V_R = 5V_{DC}$ , $f = 1MHz$

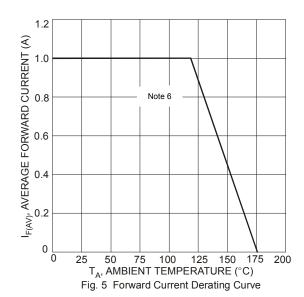
Notes:

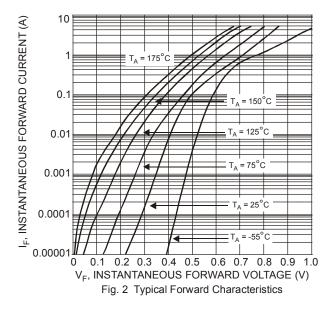
- 5. Theoretical R<sub>BJS</sub> calculated from the top center of the die straight down to the PCB/cathode tab solder junction.
- 6. Part mounted on FR-4 board with 2oz., minimum recommended copper pad layout, which can be found on our website at http://www.diodes.com.
- 7. Short duration pulse test used to minimize self-heating effect.
   8. The heat generated must be less than thermal conductivity from junction-to-ambient: dPD/DTJ < 1/RthJA</li>

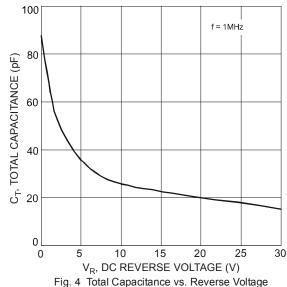












100,000

T<sub>J</sub> = 25°C

1,000

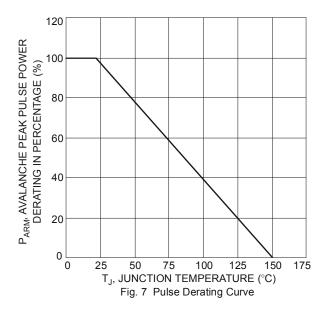
1,000

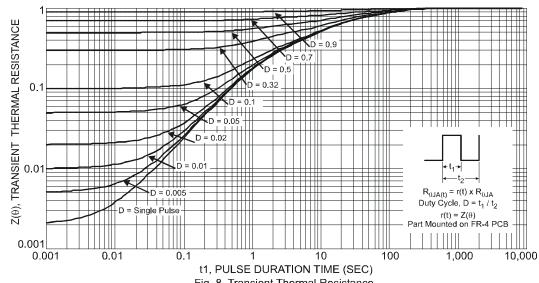
T<sub>J</sub> = 25°C

100,000

T<sub>J</sub> = 2





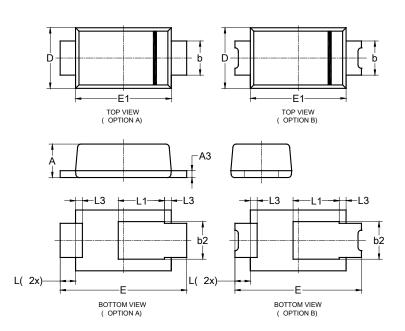




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI123

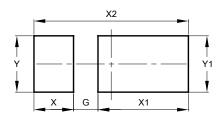


PowerDI123							
Dim	Min	Max	Тур				
Α	0.93	1.00	0.98				
A3	0.15	0.25	0.20				
b	0.85	1.25	1.00				
b2	1.025	1.125	1.10				
D	1.63	1.93	1.78				
Е	3.50	3.90	3.70				
E1	2.60	3.00	2.80				
L	0.40	0.50	0.45				
L1	1.25	1.40	1.35				
L3	0.125	0.275	0.20				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI123



Dimensions	value			
Dillielisions	(in mm)			
G	0.65			
X	1.05			
X1	2.40			
X2	4.10			
Y	1.50			
Y1	1.50			



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